

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7198	(250/306,307,310,311,492.3,492.2,492.22).ccls.	US-PGPUB; USPAT	OR	ON	2006/01/06 11:57
L2	6764	(324/750,751,754,158.1,537).ccls.	US-PGPUB; USPAT	OR	ON	2006/01/06 11:58
L3	1086	(356/334,394).ccls.	US-PGPUB; USPAT	OR	ON	2006/01/06 11:58
L4	598	(156/89.12,379).ccls.	US-PGPUB; USPAT	OR	ON	2006/01/06 11:58
L5	15446	L1 or L2 or L3 or L4	US-PGPUB; USPAT	OR	ON	2006/01/06 11:58
L6	171	L5 and ((silicon adj on adj insulator) or SOI)	US-PGPUB; USPAT	OR	OFF	2006/01/06 12:00
L7	0	L6 and (semiconductor near2 die) and (inspection with (electron or SEM))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/06 12:00
L8	40	L5 and (semiconductor near2 die) and (inspection with (electron or SEM))	US-PGPUB; USPAT	OR	ON	2006/01/06 11:59
L9	0	L8 and ((silicon adj on adj insulator) or SOI)	US-PGPUB; USPAT	OR	OFF	2006/01/06 11:59
L10	100	(semiconductor near2 die) and (inspection with (electron or SEM))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/06 12:00
L11	0	L10 and ((silicon adj on adj insulator) or SOI)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/06 12:00